New Jersey Semi-Conductor Products, Inc.

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Gold Bonded Germanium Diodes in DO-7 Package

FEATURES

Low forward voltage drop—low power consumption
Thirty years of proven reliability—one million hours mean time between failures (MTBF)
Very low noise level
Metallurgically bonded

ABSOLUTE MAXIMUM RATINGS (at 25 °C, unless otherwise specified)

Peak Inverse Voltage

30 Volts

Peak Forward Current

500 mA

Operating Temperature Range

- 65 °C to 85 °C

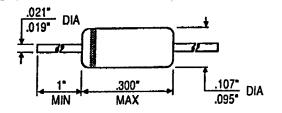
Average Power Dissipation

80 mW

ELECTRICAL CHARACTERISTICS

	Symbol	Conditions	Min	Max	Unit) T°C	l
Peak Inverse Voltage	PIV	1 mA	30		V	25 °C	
Reverse Current	lr lr	10 ·V		20	μΑ	25 °C	
Forward Voltage	Vf	2.5 mA		1	V	25 °C	
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MECHANICAL



Passes all mechanical and environmental requirements of MIL-S-19500, including shock and vibration.

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Quality Semi-Conductors